Nihon Inter Electronics Corporation

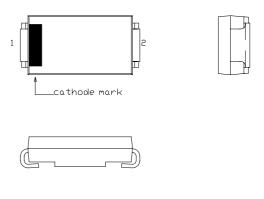
OUTLINE DRAWING

1 0 0 2

DIODE Type: NSD03A10

FEATURES

- * FLAT-PAK Surface Mount Device
- * High Surge Capability
- * Low Forward Voltage Drop
- * Low Reverse Leakage Current
- * Packaged in 16mm Tape and Reel
- * Not Rolling During Assembly



Maximum Ratings

Approx Net Weight:016g

Rating	Symbol	NSD03A10			Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	100				
Average Rectified Output Current	Io	1.57	Ta=25 °C *1	50Hz Half Sine	Λ	
		3.0	T1=108 °C *2	Wave Resistive Load	Α	
RMS Forward Current	I _{F(RMS)}	4.71			Α	
Surge Forward Current	I_{FSM}	80	50Hz Half Sine Wa	A		
		80	Non-repetitive			
Operating JunctionTemperature Range	T_{jw}	-40 to +150			°C	
Storage Temperature Range	T_{stg}	-40 to +150			°C	

Electrical • Thermal Characteristics

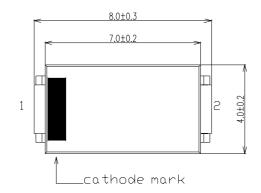
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Peak Reverse Current	I_{RM}	Tj= 25°C, V _{RM} = V _{RRM}	-	-	50	μΑ	
Peak Forward Voltage	V_{FM}	Tj= 25°C, I _{FM} = 3.0A	1	1	1.0	V	
Thermal Resistance	Rth _(j-a)	Junction to Ambient *1	İ	İ	89	°C/W	
	Rth _(j-l)	Junction to Lead	-	-	13	C / VV	

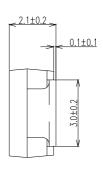
^{*1} Glass Epoxy Substrate Mounted (Soldering Lands=2x2mm,Both Sides)

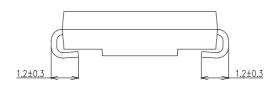
^{*2} Tl= Lead Temperature

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NSD03A10 OUTLINE DRAWING (Dimensions in mm)









SOLDERING PAD

